

# Tungsten disulfide on graphene: structural, electronic, nanotribological properties and optoelectronic applications

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In this talk recent advances on the synthesis, properties and applications of the van der Waals (vdW) heterostack tungsten disulfide ( $WS_2$ ) on graphene will be presented. It will be shown that large-area highly-crystalline monolayer  $WS_2$  can be synthesized with a vapor phase approach both on graphene arrays obtained via chemical vapor deposition (CVD) on copper (Cu) foil [1] and on epitaxial graphene on silicon carbide (SiC) [2]. It will be shown via microstructural and electronic characterization that  $WS_2$  aligns on top of graphene with a  $0^\circ$  orientation, the interface is atomically sharp and the spin-orbit splitting of monolayer  $WS_2$  on epitaxial graphene is the largest reported to date [3]. Also, experimental data and molecular dynamics simulations showing superlubric sliding of monolayer  $WS_2$  nanoflakes over epitaxial graphene triggered by a scanning tunneling microscopy (STM) tip will be presented. Finally, the fabrication of a scalable hybrid  $WS_2$ /graphene photodetector with a maximum responsivity  $R \sim 220 \text{ A}\cdot\text{W}^{-1}$  and a  $-3 \text{ dB}$  bandwidth of 250 Hz will be demonstrated [4]. In virtue of its band alignment, remarkable spin-orbit splitting, atomically sharp interface and nanotribological properties this vdW heterostack holds exciting prospects for the implementation of advanced optoelectronic multifunctional devices.

## References:

- [1] V. Miseikis, F. Bianco, J. David, M. Gemmi, V. Pellegirni, M. Romagnoli, C. Coletti, *2D Materials* 4 (2), 021004, 2017.
- [2] A. Rossi, H. Buech, C. Di Rienzo, V. Miseikis, D. Convertino, A. Al-Temimy, V. Voliani, M. Gemmi, V. Piazza, C. Coletti, *2D Materials* 3 (3), 031013, 2016.
- [3] S. Forti, A. Rossi, H. Büch, T. Cavallucci, F. Bisio, A. Sala, T.O. Montes, A. Locatelli, M. Magnozzi, M. Canepa, K. Müller, S. Link, U. Starke, V. Tozzini, C. Coletti, *Nanoscale* 9 (42), 16412-16419, 2017.
- [4] A. Rossi, D. Spirito, F. Bianco, S. Forti, F. Fabbri, H. Buech, A. Tredicucci, R. Krahne, C. Coletti, *Nanoscale* 10, 4332 – 4338, 2018.